TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

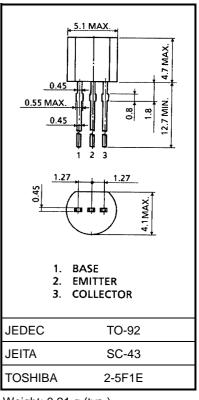
# 2SC2498

#### VHF~UHF Band Low Noise Amplifier Application

#### Unit: mm

## **Maximum Ratings (Ta = 25°C)**

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	30	V
Collector-emitter voltage	V <sub>CEO</sub>	20	V
Emitter-base voltage	V <sub>EBO</sub>	3	V
Collector current	Ic	50	mA
Base current	Ι <sub>Β</sub>	25	mA
Collector power dissipation	P <sub>C</sub>	300	mW
Junction temperature	Tj	125	°C
Storage temperature range	T <sub>stg</sub>	-55~125	°C



Weight: 0.21 g (typ.)

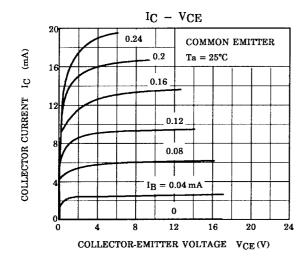
## **Microwave Characteristics (Ta = 25°C)**

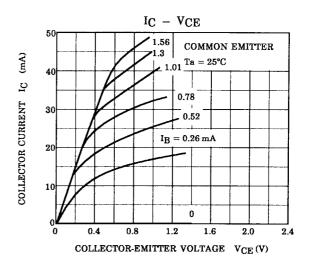
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 10 mA	_	3.5	_	GHz
Insertion gain	S <sub>21e</sub>   <sup>2</sup> (1)	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 10 mA, f = 500 MHz	_	14.5	_	dB
	S <sub>21e</sub>   <sup>2</sup> (2)	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 10 mA, f = 1 GHz	_	9	_	
Noise figure	NF (1)	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 5 mA, f = 500 MHz	_	2.5	_	- dB
	NF (2)	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 5 mA, f = 1 GHz	_	4	_	

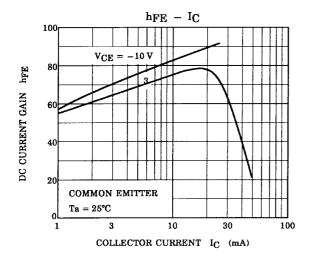
#### **Electrical Characteristics (Ta = 25°C)**

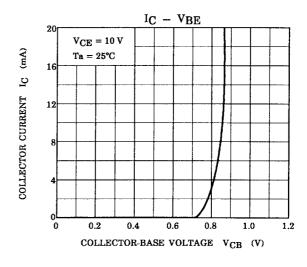
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = 10 \text{ V}, I_{E} = 0$	_	_	1	μА
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = 1 \text{ V, } I_{C} = 0$	_	_	1	μА
DC current gain	h <sub>FE</sub>	$V_{CE} = 10 \text{ V}, I_{C} = 10 \text{ mA}$	30	80	300	
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz (Note)	_	1.15	_	pF
Reverse transfer capacitance	C <sub>re</sub>		_	0.75	_	pF

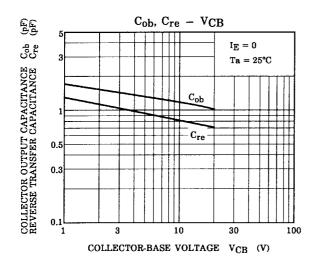
Note: Cre is measured by 3 terminal method with capacitance bridge.

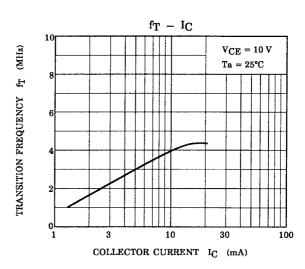




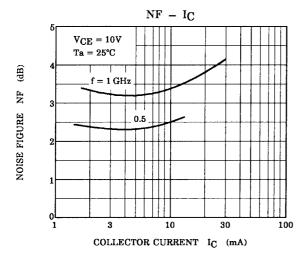


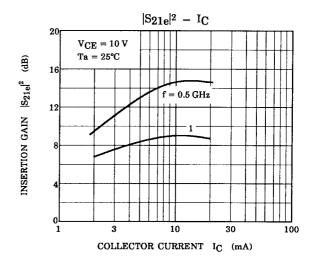


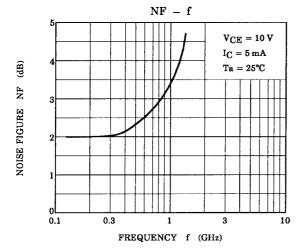


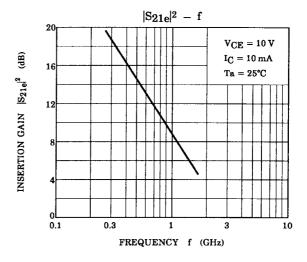


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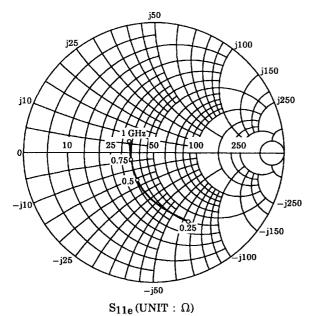


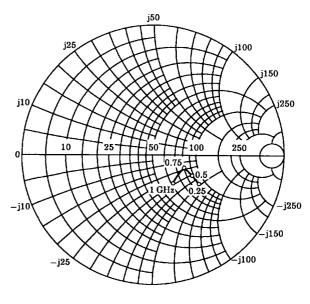




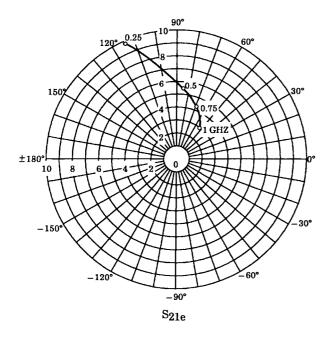
## Common Emitter Small Signal S-Parameters of 2SC2498.

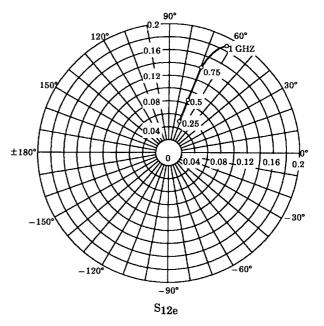
 $V_{CE} = 10 \text{ V}, I_C = 10 \text{ mA}$ 





 $S_{22e}$  (UNIT :  $\Omega$ )





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